

2SJ217

Silicon P Channel MOS FET

REJ03G0850-0200 (Previous: NON-084)

> Rev.2.00 Sep 07, 2005

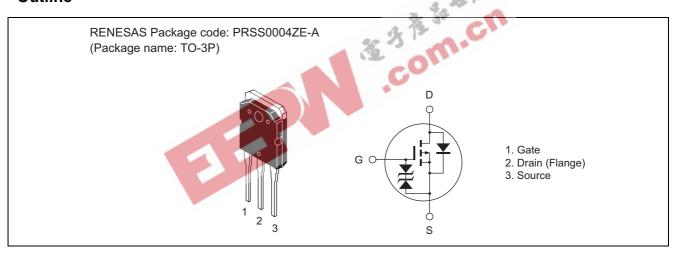
Description

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
 - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Value | Unit |
|---|-------------------------------|-------------|------|
| Drain to source voltage | V_{DSS} | -60 | V |
| Gate to source voltage | V_{GSS} | ±20 | V |
| Drain current | I _D | -45 | A |
| Drain peak current | I _{D (pulse)} Note 1 | -180 | A |
| Body to drain diode reverse drain current | I _{DR} | -45 | Α |
| Channel dissipation | Pch Note 2 | 150 | W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at $Tc = 25^{\circ}C$

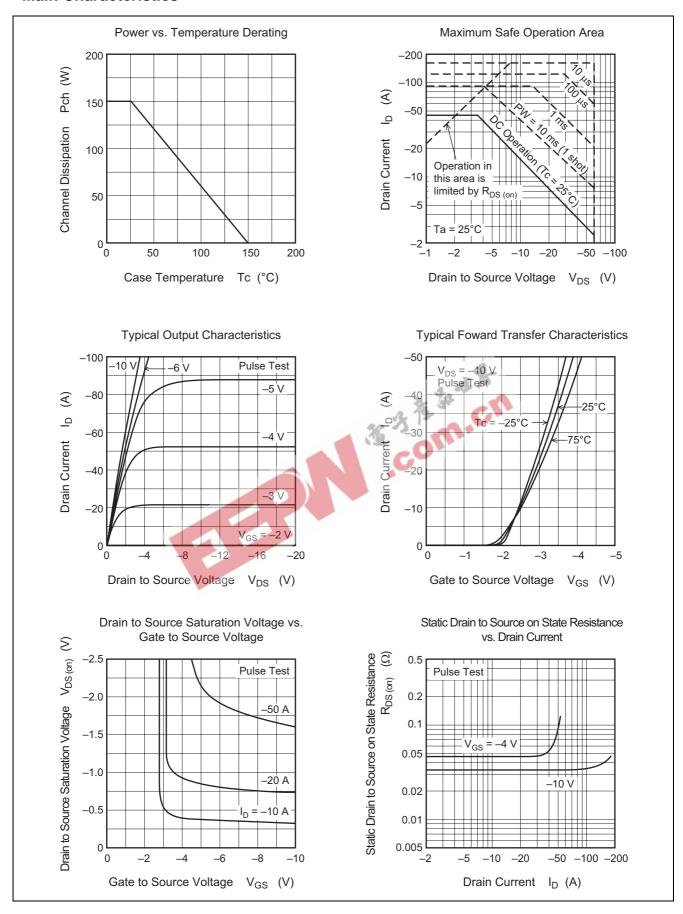
Electrical Characteristics

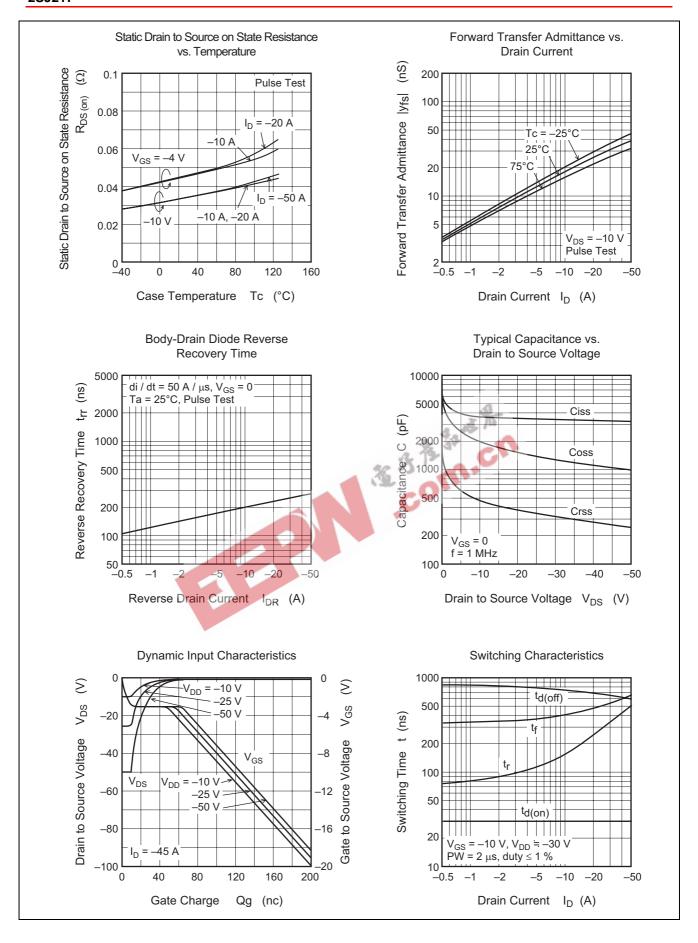
 $(Ta = 25^{\circ}C)$

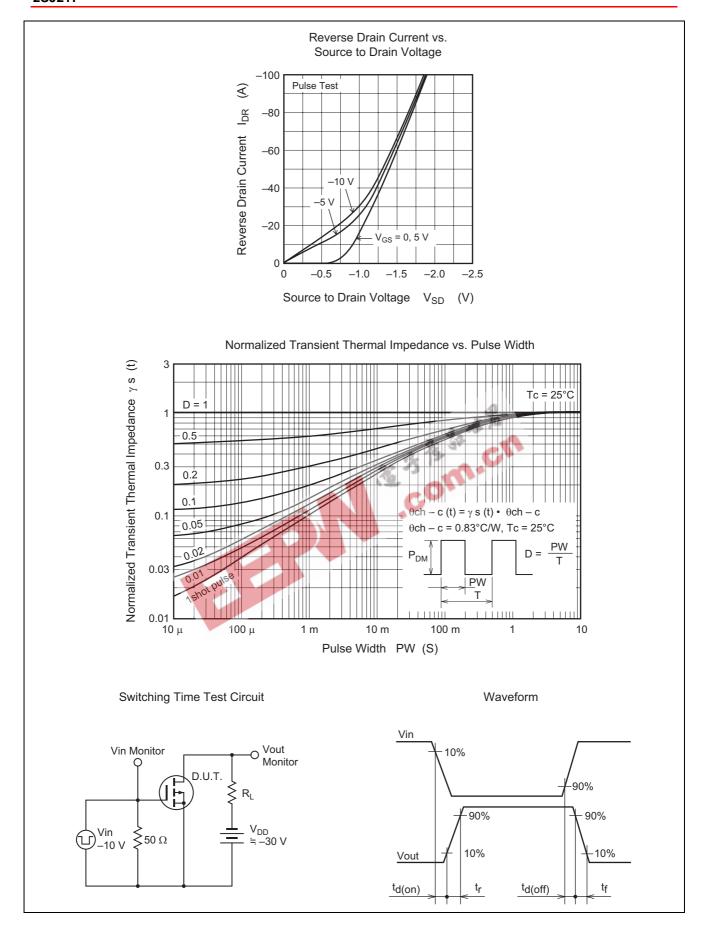
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|--|-----------------------|------|-------|-------|------|--|
| Drain to source breakdown voltage | V _{(BR) DSS} | -60 | _ | _ | V | $I_D = -10 \text{ mA}, V_{GS} = 0$ |
| Gate to source breakdown voltage | V _{(BR) GSS} | ±20 | _ | _ | V | $I_G = \pm 100 \ \mu A, \ V_{DS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | _ | ±10 | μΑ | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | _ | -250 | μΑ | $V_{DS} = -50 \text{ V}, V_{GS} = 0$ |
| Gate to source cutoff voltage | V _{GS (off)} | -1.0 | _ | -2.0 | V | $I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$ |
| Static drain to source on state resistance | R _{DS (on)} | _ | 0.033 | 0.042 | Ω | $I_D = -20 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 3}}$ |
| | R _{DS (on)} | _ | 0.045 | 0.06 | Ω | $I_D = -20 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note } 3}$ |
| Forward transfer admittance | y _{fs} | 16 | 25 | O2. | S | $I_D = -20 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note } 3}$ |
| Input capacitance | Ciss | 4 | 3800 | _ | pF | $V_{DS} = -10 \text{ V}$ |
| Output capacitance | Coss | | 2000 | _ | pF | $V_{GS} = 0$ |
| Reverse transfer capacitance | Crss | _ | 490 | _ | pF | f = 1 MHz |
| Turn-on delay time | t _{d (on)} | _ | 30 | _ | ns | $I_D = -20 \text{ A}$ |
| Rise time | tr | _ | 235 | _ | ns | $V_{GS} = -10 \text{ V}$ |
| Turn-off delay time | t _{d (off)} | _ | 670 | _ | ns | $R_L = 1.5 \Omega$ |
| Fall time | t _f | _ | 450 | _ | ns | |
| Body to drain diode forward voltage | V_{DF} | _ | -1.35 | _ | V | $I_F = -45 \text{ A}, V_{GS} = 0$ |
| Body to drain diode reverse recovery time | t _{rr} | _ | 300 | _ | ns | $I_F = -45 \text{ A}, V_{GS} = 0$ |
| | | | | | | $di_F/dt = 50 A/\mu s$ |

Note: 3. Pulse test

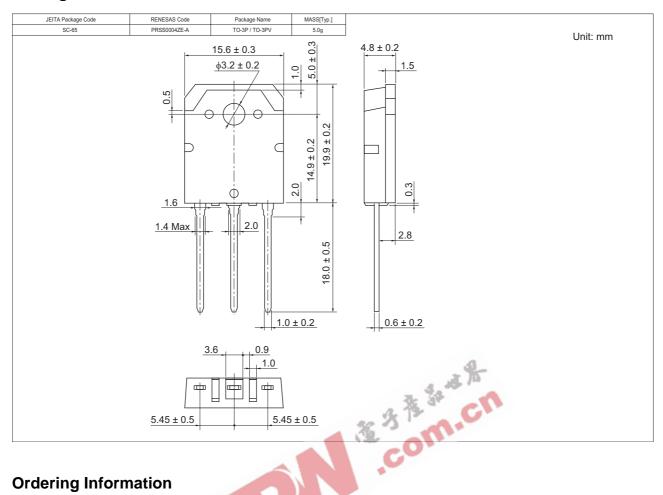
Main Characteristics







Package Dimensions



Ordering Information

| Part Name | Quantity | Shipping Container |
|-----------|----------|--------------------|
| 2SJ217-E | 30 pcs | Plastic magazine |

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